	Reg. No.						
	Question Paper Code 13136						
	DE / D Toob DECDEE EXAMINATIONS NOV / DEC 2024						
	D.E. / D. IECH DEGREE EXAMINATIONS, NOV / DEC 2024 Seventh Semaster						
	Electronics and Communication Engines	wina					
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	20ECPC/01 - RF AND MICROWAVE ENGIN	NEEKI	NG				
P	Regulations - 2020						<u></u>
Du	uration: 3 Hours			Max	. Mai	:ks: l	00
	$PARI - A (MCQ) (20 \times I = 20 Marks)$				Marks	K – Level	со
1	Answer ALL Questions	minont	1.7		1	KI	<i>CO1</i>
1.	(a) resistive (b) reactive (c) inductive (d) can	acitive	.1y	·	1	111	001
2	The canacitor preferred at high frequency is				1	K1	CO1
2.	(a) Electrolyte canacitor						
	(c) Air capacitor (d) glass capacitor						
3.	The reflection coefficient of a matched load ideally should be for perf	fect ma	tching.		1	K1	<i>CO1</i>
-	(a) Zero (b) Negative (c) Positive (d) Ir	nfinite	0				
4.	The E-plane Tee is classified as a junction.				1	K1	<i>CO2</i>
	(a) voltage (b) shunt (c) parallel (c	1) serie	s				
5.	Isolators can be made by inserting a along the axis of a recta	ngular	wavegu	uide.	1	K1	<i>CO2</i>
	(a) resistor (b) capacitor (c) ferrite rod (d) transf	former				
6.	What is the primary purpose of movable shorts in microwave enginee	ring?			1	K1	CO2
	(a) Impedance tuning and adjustment (b) Power amplif	fication	l				
	(c) Signal modulation (d) Data transmis	ssion			_		~ ~ •
7.	What is the purpose of velocity modulation in a two-cavity klystron?				1	KI	CO3
	(a) To control the transit time of electrons (b) To generate an output (c) To generate an output	put RF	signal	<i>c</i> , 1.1			
0	(c) To amplify the input RF signal (d) To create a time-va	rying n	nagneti	c field	1	V^{1}	cor
8.	which of the following factors negatively affects the performance	of vac	uum tu	bes at	1	ΓI	COS
	(a) Transit angle offects (b) Thermionic emission	ion					
	(a) Transit-angle effects (b) Thermonic efficience (c) Cathode heating (d) Anode voltage	31011					
9	The main advantage of a TWT over a klystron for microwave amplifi	cation	is		1	K1	CO3
	(a) Lower cost (b) Smaller size						
	(c) Higher power (d) Wider bandwidth						
10.	hich parameter relates incident and reflected waves in microwave circuit analysis?		?	1	K1	<i>CO</i> 4	
	(a) z parameter (b) y parameter (c) h parameter	(d) s	parame	ter			
11.	What is the range of VSWR values?			1 K1		K1	<i>CO</i> 4
	(a) Zero to one (b) One to te	en					
	(c) One to infinity (d) Zero to in	ıfinity			_		~~ .
12.	What is the main principle behind the operation of a bolometer?				1	Kl	<i>CO</i> 4
	(a) Voltage generation (b) Current an	nplifica	tion				
10	c) Resistance variation with temperature (d) Inductive coupling			1	VI	CO5	
13.	At high frequencies the output power of IMPA I I diode is				1	ΓI	COS
	(a) proportional to the frequency						
	(b) inversely proportional to the square of frequency						
	(d) proportional to the square of frequency						
14.	IMPATT diode is a				1	K1	CO5
	(a) negative resistance device (b) positive resistance	e devic	e				
	(c) zero resistance device (d) none of the ment	ioned					

15.	Identi	dentify the phenomenon responsible for the negative resistance characteristic in Gunn			K1	CO5
	diodes.					
	(a) Su	a) Superconductivity (b) Avalanche breakdown a) Ouentum tumpeling (d) Tuppeferred Electron Effect (TEE)				
16	(c) Qi	(d) If	ing (d) I ransferred Electron Effect (TEE)			CO5
10.	(a) 0.5 and 1.5 (b) 1.5 and 2.5 (c) 2.5 and 2.5 (d) 2.5 and 4.5			1	IX I	005
17	(a) 0.5 and 1.5 (b) 1.5 and 2.5 (c) 2.5 and 5.5 (d) 5.5 and 4.5 Which of the following is NOT a performance specification for an PE amplifier?			1	K1	C06
1/.	(a) Operating frequency and handwidth (in Hz) (b) Output never (in dPm)				m	000
	$(a) O_{I}$	wer supply requirements	(d) Magnetic permeability			
18	In the	n the high-frequency region, which type of filter shows a more rapid increase in insertio			K1	C06
10.	loss?			-		
	(a) Ri	nomial filters	(b) Butterworth filters			
	(a) D	aximally flat filters	(d) Equal ripple filters			
19	Deter	termine the value of power at the load of an RF amplifier if transducer pow			K2	<i>CO6</i>
17.	gain (GT) is 5.042 and the available power is 0.0308 W.					
	(a) 0.0)291 W (b) 0.987 W	(c) 0.345 W (d) 0.155 W			
20.	In the	high-frequency region, which type of filter s	hows a more rapid increase in insertion	1	<i>K1</i>	<i>CO6</i>
	loss?		1			
	(a) Binomial filters (b) Butterworth filters					
	(c) M	aximally flat filters	(d) Equal ripple filters			
		$PART - B (10 \times 2 = 2)$	20 Marks)			
Answer ALL Questions						
21.	Defin	e reciprocal and symmetrical networks.		2	K1	<i>CO1</i>
22.	Illustr	ate the equivalent circuit of high frequency ca	apacitor.	2	K1	<i>CO1</i>
23.	Defin	e coupling factor and directivity of a direction	nal coupler.	2	K1	CO2
24.	. Identify the type of component with S-parameters of S $_{11}$ =S $_{22}$ =0,S $_{21} \neq$ S $_{12}$.		of S $_{11}$ =S $_{22}$ =0,S $_{21} \neq$ S $_{12.}$	2	K1	CO2
25.	5. Compare the important features of TWTA and Klystron amplifier.		stron amplifier.	2	K2	CO3
26.	b. Define π mode of operation in magnetron.		2	K1	CO3	
27.	. State the functions of Network analyser.		2	Kl	<i>CO4</i>	
28.	. Classify microwave powers with its range.		2	KI	<i>CO4</i>	
29.	Draw the physical structure of HEMT.			2	KI	COS
30.	State	the conditions that are necessary and sufficient	nt for unconditional stability.	2	KI	006
		PART - C (6 × 10	= 60 Marks)			
		Answer ALL	Duestions			
31.	a)	State and prove the properties of S-matrix.		10	K2	CO1
	<i>,</i>	OR				
	b)	Illustrate the high frequency equivalent circ	cuit of resistor, inductor and capacitor	10	K2	CO1
		and explain.				
32.	a)	Examine the characteristics, applications ar	nd S-matrix of E-plane Tee junction in	10	K2	<i>CO2</i>
·	,	microwave Engineering.	1 5			
		OR				
	b)	Explain the operation of rat -race junction a	nd hence derive its S-parameters.	10	K2	<i>CO2</i>

33.	a)	 A Two cavity klystron amplifier has the following parameters. (a) Beam voltage V₀ =1000V, (b) DC beam resistance R₀ =35 KΩ, (c) Beam current I₀ =25 mA, (d) Operating frequency f=3 GHz (e) Gap spacing in either cavity (d)=1 mm (f) Spacing between two cavities L= 4 cm (g) Effective shunt impedance R sh =30 KΩ. Estimate the input gap voltage, voltage gain and efficiency, DC transit angle, beam coupling coefficient. 	10	K2	<i>CO3</i>
		OR			
	b)	Explain the operation of reflex klystron oscillator and derive the equation for bunching parameter with neat illustrations.	10	К2	СО3
34.	a)	Illustrate and explain the experimental set-up for dielectric constant measurement.	10	K2	<i>CO</i> 4
	b)	Illustrate the impedance, wavelength and frequency measurement using slotted line method.	10	K2	<i>CO4</i>
35.	a)	Explain the operation, construction and characteristics of IMPATT diode.	10	K2	CO5
	b)	Explain the two-valley model theory with neat illustrations.	10	K2	CO5
36.	a)	Derive the expression for input and output stability circles.	10	K2	<i>CO</i> 6
	b)	Derive the expressions for power gain, available gain and transducer gain a microwave amplifier using S-parameters.	10	K2	<i>CO</i> 6